High-Current Complementary Silicon Transistors

... for use as output devices in complementary general purpose amplifier applications.

- High DC Current Gain
 - $h_{FE} = 1000 \text{ (Min)} @ I_C = 25 \text{ Adc}$ $h_{FE} = 400 \text{ (Min)} @ I_C = 50 \text{ Adc}$
- Curves to 100 A (Pulsed)
- Diode Protection to Rated I_C
- Monolithic Construction with Built–In Base–Emitter Shunt Resistor
- Junction Temperature to +200°C

MAXIMUM RATINGS

Rating	Symbol	MJ11028 MJ11029	MJ11032 MJ11033	Unit
Collector–Emitter Voltage	V _{CEO}	60	120	Vdc
Collector–Base Voltage	V _{CB}	60	120	Vdc
Emitter-Base Voltage	V _{EB}	5		Vdc
Collector Current — Continuous Peak	I _C I _{CM}	50 100		Adc
Base Current — Continuous	Ι _Β	2		Adc
Total Power Dissipation @ $T_C = 25^{\circ}C$ Derate above 25°C @ $T_C = 100^{\circ}C$	P _D	300 1.71		Watts W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +200		°C



*ON Semiconductor Preferred Device

50 AMPERE COMPLEMENTARY SILICON DARLINGTON POWER TRANSISTORS 60–120 VOLTS 300 WATTS



THERMAL CHARACTERISTICS



Figure 1. Darlington Circuit Schematic

Preferred devices are ON Semiconductor recommended choices for future use and best overall value.

MJ11028 MJ11032 MJ11029 MJ11033

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (1)	MJ11028, MJ11029	V _{(BR)CEO}	60	_	Vdc
$(I_{\rm C} = 1 \ 00 \ {\rm mAdc}, \ I_{\rm B} = 0)$	MJ11032, MJ11033	(=:-) = = =	120	—	
Collector–Emitter Leakage Current		I _{CER}			mAdc
(V _{CE} = 60 Vdc, R _{BE} = 1 k ohm)	MJ11028, MJ11029			2	
(V _{CE} = 120 Vdc, R _{BE} = 1 k ohm)	MJ11032, MJ11033			2	
(V _{CE} = 60 Vdc, R _{BE} = 1 k ohm, T _C = 150°C)	MJ11028, MJ11029			10	
$(V_{CE} = 120 \text{ Vdc}, R_{BE} = 1 \text{ k ohm}, T_{C} = 150^{\circ}\text{C})$	MJ11032, MJ11033		_	10	
Emitter Cutoff Current ($V_{BE} = 5 \text{ Vdc}, I_{C} = 0$)		I _{EBO}	—	5	mAdc
Collector–Emitter Leakage Current ($V_{CE} = 50$ Vdc, $I_B = 0$)		I _{CEO}	—	2	mAdc
ON CHARACTERISTICS (1)					
DC Current Gain		h _{FE}			—
(I _C = 25 Adc, V _{CE} = 5 Vdc)			1 k	18 k	
$(I_C = 50 \text{ Adc}, V_{CE} = 5 \text{ Vdc})$			400	_	
Collector–Emitter Saturation Voltage		V _{CE(sat)}			Vdc
(I _C = 25 Adc, I _B = 250 mAdc)		· · ·		2.5	
$(I_{C} = 50 \text{ Adc}, I_{B} = 500 \text{ mAdc})$			—	3.5	
Base-Emitter Saturation Voltage		V _{BE(sat)}			Vdc
$(I_{C} = 25 \text{ Adc}, I_{B} = 200 \text{ mAdc})$		()	—	3.0	
$(I_{C} = 50 \text{ Adc}, I_{B} = 300 \text{ mAdc})$			—	4.5	

(1) Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

MJ11028 MJ11032 MJ11029 MJ11033



PACKAGE DIMENSIONS

CASE 197A-05 TO-204AE (TO-3) ISSUE J





2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS				
DIM	MIN	MAX	MIN	MAX			
Α	1.530 REF		38.86 REF				
В	0.990	1.050	25.15	26.67			
С	0.250	0.335	6.35	8.51			
D	0.057	0.063	1.45	1.60			
Е	0.060	0.070	1.53	1.77			
G	0.430 BSC		10.92 BSC				
Н	0.215 BSC		5.46 BSC				
K	0.440	0.480	11.18	12.19			
L	0.665 BSC		16.89 BSC				
Ν	0.760	0.830	19.31	21.08			
Q	0.151	0.165	3.84	4.19			
U	1.187 BSC		30.15 BSC				
V	0.131	0.188	3.33	4.77			

STYLE 1: PIN 1. BASE 2. EMITTER CASE: COLLECTOR

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JAPAN: ON Semiconductor, Japan Customer Focus Center 4–32–1 Nishi–Gotanda, Shinagawa–ku, Tokyo, Japan 141–0031 Phone: 81–3–5740–2700 Email: r14525@onsemi.com

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